Correlation E ects in Itinerant M agnetism

G.Gorski and J.Mizia

Institute of Physics, University of Rzeszow, ulica Rejana 16A, 35-958 Rzeszow, Poland

Abstract

In this contribution we would like to revisit the problems of ferrom agnetism (F) and antiferrom agnetism (AF) in the pure itinerant model. These methods can be extended later to the superconducting materials. In our model we assume the extended Hubbard Hamiltonian. Transition from the param agnetic state to the ordered state of magnetic nature is decided by the competition between kinetic and potential energy in which there is an increase in the kinetic energy moderated by the inter-site interactions, and a decrease in the potential energy. The competition between these two energies results in the existence of critical values of interactions for creating magnetic alignment. Only when existing in a given material interaction exceeds the critical value for a given type of ordering we can have the alignment of this type.

The in uence of inter-site correlation on F and AF in the presence of C oulom b on-site correlation is investigated. The well known Landau free energy expansion is corrected for both F and AF ordering to relect the presence of critical interaction in the second order term, which leads to the magnetic alignment.

The numerical results show that the inter-site interactions favor F at the end of the band and AF at the half-lled point. In both cases of F and AF ordering, these interactions lower substantially the C urie and N \approx l's tem - perature towards experimental data. This helps to remove the paradox in m agnetism that has persisted for a long time.

CONTENT 1. Introduction

2. The Model

2.1 Inter-site averages I = $c_i^+ c_j$

2.2 Band-width, Molecular Field and Electron Occupation

E

2.2.1 Ferrom agnetic State

222 A ntiferrom agnetic State, D iagonaliztion

- 3. Free Energy, Static M agnetic Susceptibility
- 4. Ferrom agnetism
 - 4.1 Onset of Ferrom agnetism
 - 4.2 Numerical Results for Magnetization and Curie Temperature
- 5. A ntiferrom agnetism
 - 5.1 Onset of Antiferrom agnetism
 - 5.2 Num erical Results for M agnetization and Neel's Tem perature
- 6.Conclusion

1. IN TRODUCTION

In the solids there are m any phenom ena such as band m agnetism, m etal-insulator transition, high tem perature superconductivity, which are closely related to the C oulom b correlation. To describe this correlation scientists have developed what is known today as the single band H ubbard m odel [1{3]. In the original version of this m odel only the on-site C oulom b repulsion, U = (i; i; j!/r; i) was included. The use of the sim ple m ean- eld approxim ation for this m odel led back to the Stoner m odel [4{6], in which the majority and m inority spin bands are shifted with respect to each other for the quantity E = m = U, where m is the m agnetization in B ohr's m agnetons, and the on-site C oulom b constant U plays the role of the exchange interaction. The C oulom b constant U resulting from the Stoner condition for creating ferrom agnetism is large, i.e. of the order of the bandwidth. O n one hand it can be justi ed by the existing strong C oulom b interaction, but on the other hand for such a strong interaction, one can not use the m ean- eld approxim ation.

These limitations of the mean-eld approximation started the search for a more realistic ferrom agnetic solution using higher order approximations, e.g. the Hubbard I approximation [1], coherent potential approximation (CPA) [7,8]. While the Hubbard I approximation describes correctly the atom ic limit (t = 0) it is not correct for the intermediate U=t. For these values the coherent potential approximation (CPA), which is equivalent to Hubbard III decoupling of the G reen functions, is better. Unfortunately, after a thorough analysis it was concluded that the Coulomb repulsion U, no matter how strong, does not lead to the ferrom agnetic order (see e.g., [9,10]). The reason is that it does not yield the spin dependent band shift or spin dependent band narrow ing necessary for a ferrom agnetic ordering.

Both Hubbard I and CPA approximation have two types of particles; electrons moving between empty sites and electrons moving between sites occupied by electrons of opposite spin, separated from each other by the energy U and forming lower and upper Hubbard's subbands. This is the two-pole approximation in the language of G reen functions. Base on this scheme is the newer model called \spectral density approach" (SDA) [11,12]. The magnetic phase diagrams calculated by this method are more realistic and the values of the Curie temperatures also make sense. The main advantage of SDA is to obtain a spin-dependent band shift necessary to obtain the ferror agnetic ordering. On the other side the SDA method is the linear combination of two functions leading to the real self-energy, and lacking the quasi-particle dam ping. Therefore, Nolting and co-workers have proposed a combination of

SDA and CPA called \mbox{m} odi ed alloy analogy" (MAA) [13]. This approximation has brought the self-consistent ferrom agnetic solutions, and the complex values of self-energy. The defect of this method is the small range of concentrations for which one has the ferrom agnetism and also a slightly unclear derivation of the method.

Another approach to solving the Hubbard model is computer simulation. The initial attempts of the M onte C arb simulation applied to the basic H ubbard m odel also did not give the ferrom agnetic ground state [14]. More recently, the new dynamical mean-eld theory (DMFT) [15,16] has been developed for a direct computational simulation of system s with correlated electrons on a crystal lattice. This method has the exact solution in the nontrivial lim it of an in nite coordination num ber [17]. The results have been obtained by using quantum Monte-Carlo (QMC) simulation [18(20] and the mean-eld Green function theory. Use of this dynamical mean eld theory (DMFT method), has introduced a signi cant progress in the theory of ferrom agnetism. The results (see e.g. [21,22]) show the existence of ferrom agnetism but at much lower temperatures than those coming from the Hartree-Fock approximation. Such results could remove the problem known as a \m agnetic paradox", i.e. the Curie temperature coming from the interaction constant (e.g. U) - tted to obtain the correct magnetic moment at T = 0 K - as being much too high. The later attempts along the computational lines (see $[16,20,22\{25])$) are still inconclusive, mainly for the reason of the limited size of the computational system s which seems to be too sm all too represent the bulk materials.

In recent years there has been a very fruitful analytical development in describing the magnetism by extending the Hubbard model and including into it the band degeneration and the inter-site C oulomb interactions. The in uence of inter-site interactions on the band magnetism has been studied by many authors [26{37]. They have shown how di erent inter-site interactions would a ect the ferrom agnetism in the presence of the on-site C oulomb repulsion. This also will be the subject of the present chapter.

On the experimental front in the last few years there has been discovery of a triplet superconductivity in UGe_2 [38], URhGe [39] and $ZrZn_2$ [40] materials. A lthough the transition to superconductivity takes place in very low temperatures (0.8 K), the mechanism of this phenomena is very interesting, since the superconducting pairing is (probably) stimulated by the H und's interaction (see e.g. [41]), the same one which stimulates weak itinerant ferrom agnetism. It was also found that the growing magnetic moment would suppress the superconductivity. The explanation of these facts would be quite simple; the H und's interaction stimulates both F and SC ordering, but if the ordering of a given type already takes place then it precludes the other type of ordering.

A nother type of new phenom enon which includes the band magnetism is the well documented coexistence between superconducting ordering and itinerant antiferrom agnetism in high-T_c cuprates, e.g. $YBa_2Cu_3O_{6+x}$, $La_2 \times (Sr_*Ba)_xCuO_4$. Since in these compounds the magnetic moment is stronger it suppresses the superconductivity until the moment itself disappears (see [42{44}).

Because of all these reasons of all these theoretical problem s and experim ental facts we would like in this chapter to revisit the problem s of ferrom agnetism and antiferrom agnetism in the pure itinerant m odel. These m ethods can be extended later to the superconducting m aterials, where the m agnetic ordering com petes rather than cooperates with superconductivity.

2. THE MODEL

The general model of itinerant magnetic ordering is based on the extended Hubbard quasi-single band Ham iltonian of the following form [33]

$$H = \begin{pmatrix} P \\ < ij > \\ < ij > \\ < ij > \\ + J \\ < ij > \\ ; \\ (ij >) \\ < ij > \\ (ij >) \\ < ij > \\ < ij >$$

where $_0$ is the chem ical potential, c_i^+ (c_i) creates (annihilates) the electron with spin on the i-th lattice site, $\hat{n}_i = c_i^+ c_i$ is the particle number operator for electrons with spin on the i-th lattice site, $\hat{n}_i = \hat{n}_i + \hat{n}_i$ is the charge operator, n_i is the average number of electrons on sites i with spin .

In this Ham iltonian we included not only the dom inant on-site C oulom b correlation, U, but also the on-site H und's eld F. Such a eld can exist only as the interaction between di erent orbitals in a multi-orbitalm odel. We assume the single band, but composed from identical orbitals, which are fully degenerate i.e. have the same density of states and the same electron occupation (see [10]). In such a band the electrice exchange eld can be J_{in} , where J_{in} is the exchange interaction between di erent expressed as; F = (d)1) orbitals within the same atom ic site, and d is the number of orbitals within the band. As a result our model is a quasi-single band model. The intra-atom ic Hund eld in Eq. (1) is already expressed in the Hartree-Fock approximation, which will be justied only for small values of this interaction. In addition we have three explicit inter-site interactions [1,45,46]; J-exchange interaction, J⁰-pair hopping interaction, V-density-density interaction. To avoid a large number of free parameters we will assume later on in the num erical analysis that $J^0 = J; V = 0$, which will have us with only two parameters; J and parameter S representing kinetic interactions (see Eq. (5)).

The spin dependent correlation hopping t_{ij} depends on the occupation of sites i and j, and in the operator form can be expressed as

$$t_{ij} = t(1 \quad \hat{n}_i \)(1 \quad \hat{n}_j \) + t_1 \left[\hat{n}_i \ (1 \quad \hat{n}_j \) + \hat{n}_j \ (1 \quad \hat{n}_i \) \right] + t_2 \hat{n}_i \ \hat{n}_j \quad ; \quad (2)$$

where t is the hopping am plitude for an electron of spin when both sites iand j are empty. Param eters; t_1 , t_2 , are the hopping am plitudes for an electron of spin when one or both of the sites i or j are occupied by an electron with opposite spin, respectively. Quite recently, several authors have suggested that the expected relation; $t > t_1 > t_2$, may be reversed for large enough inter-atom ic distances; $t < t_1 < t_2$ (see R efs. [47] and [48]). This concept would t the results of G unnarsson and Christensen [49], who for the heavier elements (e.g. 3d or 4f) claim growing hopping integrals with increasing occupation.

Including the occupationally dependent hopping given by Eq. (2) into the Ham iltonian (1) we obtain the following result

where

$$t = t t_1$$
; $t_{ex} = \frac{t + t_2}{2} t_1$: (4)

In this form it is quite visible that the kinetic interactions: the hopping interaction, t_{ex} , and the exchange hopping interaction, t_{ex} , are also the inter-site interactions.

We assume that $t_1/t = S$ and $t_2/t_1 = S_1$. In general these parameters are dimensioned and they both full the condition S < 1 and $S_1 < 1$ which is equivalent to $t > t_1 > t_2$ (see Ref. [47]). For simplicity we will assume now additionally that $S = S_1$. With this assumption we have the relationships

$$t = t \quad t_1 = t(1 \quad S) ; \quad t_{ex} = \frac{t + t_2}{2} \quad t_1 = \frac{t}{2} (1 \quad S)^2 :$$
 (5)

In the Ham iltonian (3) there are many inter-site interactions: $t;t_{ex};J;J^{0};V$, for which we will use the modi ed Hartree-Fock (H-F) approximation. For the two- and three-body terms of Ham iltonian we will adopt the procedure introduced by Foglio and Falicov [50], A ligia and co-workers [51], and Hirsch [27]. Neglecting superconductive averages of the type: $c_{i}^{+}c_{j}^{+}o$, $hc_{i}c_{j}oi$, and the spin- ip terms $c_{i}^{+}c_{j}$ we obtain

-e.g. for two-body term

$$\hat{n}_{i}\hat{n}_{j} = (\hat{n}_{i''} + \hat{n}_{i\#}) (\hat{n}_{j''} + \hat{n}_{j\#}) = h\hat{n}_{\underline{i}''} + \hat{n}_{i\#}i (\hat{n}_{j''} + \hat{n}_{j\#}) + (\hat{n}_{i''} + \hat{n}_{i\#}) h\hat{n}_{j''} + \hat{n}_{j\#}i c_{i}^{\dagger} c_{j} c_{j}^{\dagger} c_{i} + hc: + const ; (6)$$

-e.g. for three-body term

$$c_{i''}^{+}c_{j''}\hat{n}_{i\#}\hat{n}_{j\#} = c_{i''}^{+}c_{j''}c_{i\#}^{+}c_{i\#}c_{j\#}^{+}c_{j\#} = c_{i''}^{+}c_{j''} h\hat{n}_{i\#}ih\hat{n}_{j\#}i - c_{i\#}^{+}c_{i\#}c_{j\#} - c_{i\#}^{+}c_{i\#}c_{j\#} - c_{i\#}^{+}c_{i\#}c_{j\#} - c_{i\#}^{+}c_{i\#}c_{j\#} - c_{i\#}^{+}c_{i\#}c_{i\#} - c_{i\#}^{+}c_{i\#}c_{i\#}c_{i\#} - c_{i\#}^{+}c_{i\#}c_{i\#}c_{i\#}c_{i\#} - c_{i\#}^{+}c_{i\#}$$

D The main point of this approximation is to retain the following inter-site averages: I = $c_i^+ c_j^-$, in addition to the usual on site averages: $n_i^- = h\hat{n}_i^- i$, which contribute to the Stoner eld.

A fler perform ing this modi ed H artree-Fock approximation on all inter-site interactions: $t;t_{ex};J;J^0;V$, we obtain the following simplied H am iltonian

$$H = \begin{pmatrix} X \\ t_{eff} \\ ij \end{pmatrix} \begin{pmatrix} c_{i}^{+} \\ c_{j} \\ i \end{pmatrix} + h \\ c_{i} \\ c_{$$

where $t_{eff} = t$ b is the elective hopping integral, with b given by

$$b = 1 \frac{t}{t} (n_{i} + n_{j}) + 2 \frac{t_{ex}}{t} n_{i} n_{j} I^{2} 2II \frac{J V}{t} I \frac{J + J^{0}}{t} I;$$
(9)

and M $_{\rm i}$ is the spin-dependent m odi ed m olecular eld for electrons with spin expressed as

$$M_{i} = F n_{i} \quad J \quad n_{j} + V \quad (n_{j} + n_{j}) + 2z t I \qquad 2t_{ex}I \quad n_{j} ; \quad (10)$$

where z is the number of the nearest neighbors, P_j is the sum over nearest neighbors of the lattice site i. The above molecular eld is the sum of the on-site contribution F and the inter-site contributions, which will be di erent for F and AF.

2.1 IN TER-SITE AVERAGES I =
$$c_i^+ c_j^-$$

Parameter I can be calculated from the average kinetic energy. In the case of ferrom agnetism one can write the following expression for the average kinetic energy of + electrons hK i

$$hK i = t_{eff} C_i^{\dagger} C_j = zt_{eff} I = D_{eff} I ; \qquad (11)$$

where $D_{eff} = zt_{eff}$ is the half band-width of the + electrons.

The kinetic energy can be calculated straightforward as

$$hK = \int_{D}^{D} f^{\mu} u^{0} u^{0} u^{0} d^{\mu} = D_{eff}I ; \qquad (12)$$

with " ("⁰) = b "⁰ being the energy of the deform ed band, "⁰ is the energy of unperturbed band with all inter-site interactions being equal to zero, and f [" ("⁰)] = $\frac{1}{1+e^{[" ("^0)]/kT}}$ is the Ferm i function. Eq. (12) m eans that we can calculate the average product of two nearest neighbor operators: I = hK i=D_{eff}.

In the case of zero tem perature, T = 0 K, and constant density of state (DOS): 0 ("⁰) = const = $\frac{1}{D}$ for D 0 D (D = zt - unperturbed half-bandwidth), we obtain from Eq. (12) that

$$I = n (1 n)$$
 : (13)

This approximation suggests that we can treat the average $I = \begin{bmatrix} D & E \\ c_i^{\dagger} & c_j \end{bmatrix}^{E}$ as the probability of electron with spin hopping from the i to the j lattice site and back. More precisely, it is given by the average of two products. One is the product of probabilities that there is an electron with spin on the i site and that the j site has empty states; $\frac{n_i & (n_j^{t} & n_j)}{n_i + (n_j^{t} & n_j)}$, and the second one is the probability of the opposite jump; $\frac{n_j & (n_i^{t} & n_i)}{n_j + (n_i^{t} & n_i)}$. The quantity n_i is the average number of electrons in the sub-band on sites i and n_i^{t} is the total capacity of the opposite jump; called I, is given by the average of above probabilities

$$I = \frac{1}{2} \left[\frac{\mathbf{n}_{i}}{\mathbf{n}_{i}} + (\mathbf{n}_{j}^{t} - \mathbf{n}_{j}) + \frac{\mathbf{n}_{j}}{\mathbf{n}_{j}} + (\mathbf{n}_{i}^{t} - \mathbf{n}_{i}) + \frac{\mathbf{n}_{j}}{\mathbf{n}_{j}} + (\mathbf{n}_{i}^{t} - \mathbf{n}_{i}) \right]^{\#} : \qquad (14)$$

For the weak correlation (U << D), when the band is not split by the C oulom b repulsion, we have $n_{\rm i}^{\rm t}$ = 1 and $n_{\rm i}$ = $n_{\rm i}$

$$I = \frac{1}{2} \frac{n_{i} (1 - n_{j})}{n_{i} + (1 - n_{j})} + \frac{n_{j} (1 - n_{i})}{n_{j} + (1 - n_{i})}^{\#} \qquad (15)$$

Expressions (14) and (15) give a general form of quantity I , which depend on the type of magnetic ordering and on the strength of C oulomb on-site interaction through the mean values n_i and n_j .

At 1st let us consider the quantity I in the ferrom agnetic state when one has the obvious relation; $\mathbf{n}_i = \mathbf{n}_j$. In the case of a weak correlation (U << D) the band is not split and for the electrons with spin we have; $\mathbf{n}_i = \mathbf{n}_i$ n, and expression (15) can be simplified to Eq. (13).

In the case of strong correlation (U >> D) when the band is split into the lower and the upper H ubbard sub-band, quantities n_i and n_i^t , will depend on the location of the chem ical potential. When n < 1 the chem ical potential is located in the lower H ubbard sub-band and we have; $n_i = n$, $n_i^t = 1$ n, what gives for I the result

$$I = \frac{n (1 n)}{1 n} ;$$
 (16)

-for the upper Hubbard sub-band (n > 1) we have: $n_i = n$ (1 n) = n 1, $n_i^t = n$ and I is equal to

$$I = \frac{(n \ 1)(1 \ n)}{n} :$$
 (17)

In the antiferrom agnetic state the crystal lattice will be divided into two interpenetrating sub-lattices; ; with opposite spins, and with the average electron numbers equal to

$$n = n = \frac{n m}{2}$$
; $n = n = \frac{n m}{2}$; (18)

where m is the antiferrom agnetic m om ent per atom in B ohr's m agnetons.

The indices i; j belong to the neighboring sub-lattices ; with opposite m agnetic m oments. In the result for AF ground state the parameter; I = I I_{AF} is spin independent (i.e. it does not depend on the rst power of antiferrom agnetic m oment m)

The parameter $I_{\rm A\,F}\,$ for the weak correlation is calculated from Eq. (15) using values of n $^{(\)}$ from Eq. (18)

$$I_{AF} = \frac{2n n^2 m^2}{4(1 m^2)} :$$
 (19)

For the strong correlation and the chem ical potential located in the lower sub-band $(n \ 1)$, we obtain from Eq. (14) that

$$I_{AF} = \frac{(2n \ n^2 \ m^2) \ (1 \ n)}{(2 \ n)^2 \ m^2} ; \qquad (20)$$

and for the upper sub-band

$$I_{AF} = \frac{(n \ 1)(2n \ n^2 \ m^2)}{n^2 \ m^2} \quad : \tag{21}$$

A fler calculating the quantity I for F and I_{AF} for A F ordering we can distribute the bandwidth parameter, b, and the modied molecular eld, M_i, which are present in the H am iltonian of Eq. (8).

2.2 BAND-W IDTH, MOLECULAR FIELD AND ELECTRON OCCUPA-TION

2.2.1 FERROM AGNETIC STATE

In the ferrom agnetic state the electron concentration is the same on each lattice site: $n_i = n_j = n$, and the spin dependent parameter I in the case of weak C oulomb correlation is given by Eq. (13), and Eqs (16) or (17) in the case of the strong correlation. Inserting those values into Eqs (9) and (10) we have

$$b = 1 \quad 2\frac{t}{t}n + 2\frac{t_{ex}}{t}n^2 \quad I^2 \quad 2II \quad \frac{J \quad V}{t}I \quad \frac{J + J^0}{t}I ;$$
 (22)

$$M_{i} M = (F + zJ)n + zVn + 2zI (t t_{ex}n)$$
 : (23)

Using Eq. (5) we can simplify Eq. (22) to the form

$$b = 1 2 (1 S)n + (1 S)^{2} n^{2} I^{2} 2II \frac{J V}{t}I \frac{J + J^{0}}{t}I : (24)$$

The elective total eld in a ferrom agnetic state, F $_{tot}^{F}$, can be found now from the W eiss assumption that the energy shift between both spin sub-bands, E, is equal to this eld multiplied by the existing magnetic moment

$$E = M \qquad M = F_{tot}^{F} m ; \qquad (25)$$

which after assuming the Eq. (13) for I gives

$$F_{tot}^{F} = F + z[J + t_{ex}\frac{n^{2} m^{2}}{2} + 2 t(1 n)]$$
 : (26)

In analyzing the H am iltonian (8) for the appearance of ferrom agnetism we will use the level of approximation which will modify the $D \circ S$, in addition to its shift by the molecular eld.

A fler Fourier transform of the kinetic energy the H am iltonian (8) takes on the following form

$$H = \bigvee_{k}^{X} (\mathbf{''}_{k} + M) \hat{\mathbf{n}}_{k} + U \bigvee_{i}^{X} \hat{\mathbf{n}}_{i} \hat{\mathbf{n}}_{i}$$
(27)

with the spin dependent electron dispersion relation given by

$${\bf u}_{k} = {\bf u}_{k}^{0} {\bf b}$$
 ; (28)

where b and M for the ferrom agnetic state are given by Eqs (22) and (23), and $"^0_k$ is the initial dispersion energy of the electron (without the inter-site interactions)

$$\mathbf{u}_{k}^{0} = t_{(i,j)}^{X} e^{ik (R_{i} R_{j})}$$
: (29)

The Ham iltonian (27) is solved in the CPA approximation (see [8,52]), which produces the following equation for the on-site self-energy (")

$$(1 n) \frac{U}{1 + F(")} + n \frac{U}{1(U)F(")} = 0$$
; (30)

with the spin dependent Slater-Koster function F (") which can be written as

$$F (") = \frac{1}{N} \frac{X}{k} \frac{1}{m - \frac{1}{k} M} + (31)$$

This function F (") can be expressed by the unperturbed function

$$F_{0}(") = \frac{1}{N} \frac{X}{k} \frac{1}{m} \frac{1}{k} ;$$
 (32)

by the help of the following relation

$$F (") = \frac{1}{b} F_0 \frac{" M + }{b} ; \qquad (33)$$

which becomes the standard CPA relation: $F(") = F_0(" M +)$, when all the inter-site interactions are zero and as a result b 1. The above de ned Slater-Koster function was obtained from the solution of the CPA equation and depends on the spin orientation and on the on-site interaction, U, and the inter-site interactions.

For the unperturbed Slater-K oster function we have the relation [B]

$$(") = \frac{1}{2} \operatorname{Im} F_{0} (") :$$
 (34)

U sing the identity

$$(") = \frac{1}{-} \operatorname{Im} F (")$$
 (35)

one can calculate the perturbed DOS depending on the on-site Coulomb correlation U through the self-energy , and on the inter-site interactions through the band-width parameter b .

U sing this D O S one can write the expression for electron occupation in the ferrom agnetic state

n =
$$\binom{2}{1}$$
 (") $\frac{d"}{1 + e^{(" + M)/kT}}$; (36)

where (") is the spin dependent density of states given by Eq. (35), and the previous CPA equations.

The electron occupation number and the magnetization are given by

$$n = n + n \quad ; \tag{37}$$

$$\mathbf{m} = \mathbf{n} \quad \mathbf{n} \quad : \tag{38}$$

2.2.2 ANTIFERROM AGNETIC STATE, DIAGONALIZATION

In the antiferrom agnetic state the magnetic moment on the nearest lattice sites is opposite with respect to each other (see Eqs (18)), the quantity $I = I = I_{AF}$, and the bandwidth reduction parameter b from Eq. (9) is spin independent

$$b = b = b^{AF} = 1 \quad \frac{t}{t}n + 2\frac{t_{ex}}{t} \quad \frac{n^2 \quad m^2}{4} \quad 3I^2_{AF} \quad \frac{2J + J^0 \quad V}{t}I_{AF} \quad (39)$$

A fler expressing the kinetic term s by a factor S de ned in Eq. (5) it takes on the form

$$b^{AF} = 1 (1 S)n + (1 S)^2 \frac{n^2 m^2}{4} 3I_{AF}^2 \frac{2J + J^0 V}{t}I_{AF}$$
 (40)

The generalized (modied) molecular eld from Eq. (10) depends on the spin and on the sub-lattice index: or . For the sub-lattice we have

$$M = F n \quad z (J + 2t_{ex}I_{AF}) n + zV n + 2z tI_{AF} ; \qquad (41)$$

and for the sub-lattice

Now, we can calculate the elective total eld on the sites ; in a similar way to the case of ferrom agnetism

$$F_{tot}^{AF} = \frac{M}{m} = \frac{M}{m} = F z (J + 2t_{ex}I_{AF}) :$$
 (43)

This equation shows that the positive inter-site exchange interaction, J, and exchangehopping interaction, t_{ex} , are opposing AF. It is contrary to the case of ferrom agnetism (see Eq. (26)), where both these interactions (when positive) are helping the ferrom agnetism.

A s m entioned above we assume the type of the crystal lattice, which can be divided into two interpenetrating sub-lattices: ; , with the average electron num bers given by Eqs (18).

For the AF ground state we use the diagonalization of P lischke & M attis [53], B rouers [54] and M izia [55]. The Ham iltonian (8), after taking into account Eqs (39)-(42), will take on the following form

$$H = t_{eff} + t_{i} + t_{i}$$

where $_{i}^{+}(_{i})$ and $_{i}^{+}(_{i})$ are the creation (annihilation) operators for an electron of spin on the sub-lattice and respectively, $\hat{n}_{i} = _{i}^{+} _{i}$ is the electron number operator for electrons with spin on the sub-lattice = ; , $t_{eff} = t$ b^{F} is the electric hopping integral.

Now we will derive the equations for dispersion relation, particle number and m agnetization in the antiferrom agnetic state using H am iltonian (44) and the G reen function technique. For the on-site interaction, U, we use the standard CPA approximation, which for simplicity, in further analysis, is treated in the weak and strong correlation limits. For the weak correlation we use a rst order approximation in interaction constant over the bandwidth. This is equivalent to the Hartree-Fock approximation. The second case is the high correlation approximation, U >> D, which will be easy to extend for the arbitrary strength of the on-site interaction later on.

The main idea of the CPA formalism [8] is used now. We split the above stochastic Hamiltonian (44) into a homogeneous part

$$H_{0} = t_{eff} + t_{i} + t_$$

and a stochastic part

$$H_{I} = \bigvee_{i}^{X} (\nabla) \hat{n}_{i} + \bigvee_{i}^{X} (\nabla) \hat{n}_{i} ; \qquad (46)$$

where

$$= _{0} zVn 2z tI_{AF}$$
(47)

is the electric chemical potential, are the self energies on sites = ; for electrons with spin and ∇ ⁽⁾ are the stochastic potentials given by

$$\nabla^{()} = \begin{pmatrix} \nabla_{1}^{()} = Fn^{()} & z(J + 2t_{ex}I_{AF})n^{()} \\ \nabla_{2}^{()} = U & Fn^{()} & z(J + 2t_{ex}I_{AF})n^{()} \end{pmatrix}, \text{ with probabilities} \begin{pmatrix} P_{1}^{()} = 1 & n^{()} \\ P_{2}^{()} = n^{()} \\ P_{2}^{()} = n^{()} \end{pmatrix}$$
(48)

The self-energies ful 11 the CPA equations

$$\sum_{i=1}^{X^{2}} P_{i} \frac{\tilde{V}_{i}}{1 \quad \tilde{V}_{i}} \quad F('') = 0 , \text{ for } = ();$$
 (49)

with the Slater-Koster function F (") for the sub-lattice in the following form

$$F (") = \frac{1}{N} \sum_{k}^{X} G (";k) ;$$
 (50)

and G (";k) given by Eq. (55) below.

A fter dropping the param agnetic part the stochastic potential (48) takes on the follow ing form

$$\nabla^{()} = \begin{array}{c} \nabla_{1}^{()} = \\ \nabla_{2}^{()} = \\ \end{array}, \text{ with } \begin{array}{c} P_{1}^{()} = 1 \\ P_{2}^{()} = n \end{array};$$
(51)

where

$$n = \frac{n m}{2} ; = F_{tot}^{AF} \frac{m}{2} , \text{ and } F_{tot}^{AF} = F z (J + 2t_{ex} I_{AF}) :$$
 (52)

This simplication of the Eq. (49) allows to see that the self-energies full the relations; = _____+, and = . Therefore the solution of the problem can be reduced to noting only the self-energies, . The interpretation of the parameter as the antiferrom agnetic energy gap will be given below.

We transform Hamiltonian (45) into the momentum space, and use it in the equations of motion for the G reen functions

"
$$hhA; B ii_{II} = [A; B]_{II} + [A; H_{0}]; B_{II};$$
 (53)

where (A; B) 2 $\binom{+}{k}$; $\binom{+}{k}$; $\binom{+}{k}$; As a result the following equations are obtained

"+ "_k "_k "G (";k) G (";k) =
$$\begin{bmatrix} 1 & 0 \\ 0 & 1 \end{bmatrix}$$
; (54)

with e.g. G (";k) = << k; k >>, G (";k) = << k; k >>.

Solving this set of equations we arrive at the following expressions for the G reen functions

$$G^{()}(";k) = \frac{1}{2} \frac{1}{2} \frac{"+}{"+} \frac{()}{()} [G^{("_{eff};k)} G^{(("_{eff};k)]}; (55)]$$

with

$$"_{eff} = \frac{q}{(" + _{+})(" + _{+})};$$
(56)

and G ("eff;k) given by

G
$$("_{eff};k) = \frac{1}{"_{eff}} ; k = "_{k}^{0} b^{AF}$$
 : (57)

Remembering that

$$(") = \frac{1}{2} \operatorname{Im} [F (")]$$
 (58)

we obtain

$${}^{()} = \frac{1}{2} \operatorname{Im}^{\frac{V_{u}}{U}} \frac{\frac{W_{u}}{W_{u}}}{\frac{W_{u}}{W_{u}}} \frac{\frac{W_{u}}{W_{u}}}{\frac{W_{u}}{W_{u}}} \frac{1}{b^{AF}} F_{0} \frac{W_{u}}{b^{AF}} \frac{1}{W_{u}} \operatorname{Im} F ;$$
(59)

where F_0 (") is the unperturbed Slater-K oster function given by Eq. (32).

U sing Eq. (50) we obtain the expressions for electron numbers

$$n = \int_{1}^{2^{4}} \frac{1}{1 + e^{"/kT}} - \frac{1}{m} [F (")]d" = \frac{1}{N} \int_{k-1}^{x} \frac{2^{4}}{1 + e^{"/kT}} - \frac{1}{m} [G (";k)]d" : (60)$$

Treating the self-energies as the solutions of Eq. (49), and using it only in the rst order approximation with respect to the Coulomb on-site repulsion, U, we obtain

$$= = \sum_{i=1}^{X^{2}} P_{i} \quad \forall_{i} = [U \quad F \quad z (J + 2t_{ex} I_{AF})] \frac{n}{2} ; \qquad (61)$$

where the antiferrom agnetic energy gap is given by the expression

$$= \overset{h}{U} + F_{tot}^{AF} \overset{i}{\frac{m}{2}} :$$
 (62)

This expression is dimension Eq. (52) by adding to the elective eld the Coulomb repulsion, U, which in the case of the weak interaction is also treated in the Hartree-Fock approximation.

Neglecting the param agnetic part in self-energies we have

Inserting these self-energies into Eq. (55) and rede ning "+ as "we obtain

$$G^{()}(";k) = \frac{1}{2} \frac{s}{m} [G^{("_{eff};k)} G^{("_{eff};k)}] :$$
(64)

From this equation using Eqs (50) and (58) one can obtain the following relation for the DOS on sites ;

$$() (") = \frac{s}{\frac{m}{m}} ("_{eff}) (") :$$
 (65)

In this form it is evident that the AF DOS will vanish between energies and + (zero energy was assumed in the center of the atom ic band or approximately at the atom ic level). Hence, the quantity is the AF energy gap. The schematic shape of the DOS is shown in Fig. 1.

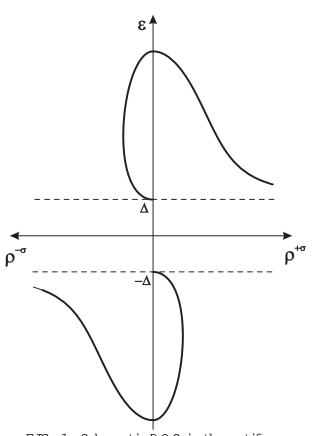


FIG.1. Schem atic $\bar{\rm D}\,O\,S$ in the antiferrom agnetic state. The energy gap extends from \$ to + .

FIGURES

One can be prove that if the old distribution is norm alized to unity;

$$z^{p}$$
 ("⁰)d"⁰ = 1 ; (66)

then the new one given by Eq. (65) is also norm alized.

Since $_+$ (") = ("), one can write that

$$p_{\frac{D_{gff}^{2}+2}{D_{eff}^{2}+2}} = p_{\frac{D_{eff}^{2}+2}{D_{eff}^{2}+2}}^{p_{\frac{D_{eff}^{2}+2}}} \frac{p_{\frac{D_{eff}^{2}+2}}{D_{eff}^{2}+2}}{p_{\frac{D_{eff}^{2}+2}^{2}}} \left[+ (") + (") \right] d" = \frac{1}{2} p_{\frac{D_{eff}^{2}+2}}^{p_{\frac{D_{eff}^{2}+2}}} \left[+ (") + (") \right] d" ;$$
(67)

where $D_{eff} = zt$ b^F . Inserting

$$_{+}(") + (") = \overset{0}{e} \frac{\pi}{"+} + \overset{s}{} \frac{\pi}{"+} A ("_{eff}) \frac{2}{"_{eff}} ("_{eff})$$
(68)

and using the identity obtained from Eq. (56); $d'' = \frac{d''_{eff}}{d''_{eff}} d''_{eff}$, one obtains from Eq. (67)

$$P \frac{D_{Z^{\text{eff}}}^{2} + 2}{D_{Z^{\text{eff}}}^{2} + (")d"} = \frac{D_{Z^{\text{eff}}}}{D_{eff}} + ("_{eff})d"_{eff} = 1 : (69)$$

Restricting as before only to the rst order approximation for the self-energies (Eq. (63)) in Eq. (60) we obtain the following expressions for electron numbers

$$n = n = \frac{1}{2N} \sum_{k}^{k} P_{k} f(E_{k}) + P_{k} f(E_{k})^{i};$$
(70)

where f (E $_{\rm k}$) is the Ferm i function

$$f(E_k) = \frac{1}{1 + e^{(E_k)/kT}} ;$$
 (71)

$$E_{k} = \frac{q_{k}}{m_{k}^{2} + 2}$$
; $S_{k} = \frac{s_{k}}{E_{k}}$; (72)

and

$$P_{k} = \frac{"_{k}S_{k}}{E_{k}}$$
(73)

is the occupation probability of state (k;).

The expression for electron occupation in the antiferrom agnetic state in the presence of external eld H will be di erent from Eq. (36), which was suitable for ferrom agnetism. Now, the external eld will act di erently on both spins in two sub-lattices and . Therefore its energy has to be included into the energy of the internal exchange eld in the process of diagonalization. It will result in the following form ula for the electron occupation on the sub-lattice

n =
$$\int_{1}^{2^{4}} (";x) \frac{d"}{1 + e^{(")/kT}}$$
, where x = + _BH: (74)

The precise form of the density of states () (") comes from Eq. (59) (or (65) in the case of the Hartree-Fock approximation). As it can be seen, it depends on the initial DOS and on the result of the diagonalization of two sub-lattices Ham iltonian.

3. FREE ENERGY, STATIC MAGNETIC SUSCEP-TIBILITY

For a simple magnetic material, the free energy can be written

$$F_{m} = F_{0} + a_{2}m^{2} + a_{4}m^{4} + \dots = F_{0} + a_{B}m^{2} = a_{4}m^{4} + \dots$$
(75)

with being the magnetic susceptibility.

The electron occupation of the ferrom agnetic state in the presence of an external magnetic eld H is given by the expression (36) with added shift from the magnetic eld

$$n = \int_{1}^{Z^{4}} (") \frac{d"}{1 + e^{(" + M_{B}H)/kT}} ;$$
 (76)

where $_{\rm B}$ is the Bohrmagneton.

The magnetic susceptibility is given by

$$= {}_{B} \frac{(n n)}{(2 H)} {}_{H=0}^{1} (77)$$

As a result of inserting Eq. (76) into it we arrive at the following equation for the static ferrom agnetic susceptibility

.

$$= \frac{2 \frac{2}{B} I_{T}}{1 K F_{tot}^{F} I_{T}} ; \qquad (78)$$

where K is the correlation factor de ned m athem atically by the following equation

$$K = {\begin{array}{*{20}c} \mathbb{R} & \frac{\mathbb{Q} & (")}{\mathbb{Q}m} \frac{\mathrm{d}"}{1 + \mathrm{e}^{(" + M)/kT}} & \frac{\mathbb{R}}{1} \frac{\mathbb{Q} & (")}{\mathbb{Q}m} \frac{\mathrm{d}"}{1 + \mathrm{e}^{(" + M)/kT}} \\ & = 2 {\begin{array}{*{20}c} \mathbb{R} & \frac{\mathbb{Q} & (")}{\mathbb{Q}m} \frac{\mathrm{d}"}{1 + \mathrm{e}^{(" + M)/kT}} \end{array}} ; \quad (79)$$

 F_{tot}^{F} is the total Stoner exchange eld, which on the base of Eq. (25) can be written as

$$\mathbf{F}_{\text{tot}}^{F} = \frac{\mathbf{Q}\mathbf{M}}{\mathbf{Q}\mathbf{m}} \frac{\mathbf{Q}\mathbf{M}}{\mathbf{m} \cdot \mathbf{0}} = 2\frac{\mathbf{Q}\mathbf{M}}{\mathbf{Q}\mathbf{m}} \mathbf{m} \cdot \mathbf{0}; \qquad (80)$$

I.

and

$$I_{T} = \int_{m=0}^{Z^{2}} (") P_{T} (") d"; P_{T} (") = \frac{\varrho f (")}{\varrho "} = f^{2} (") e^{(")/kT} \frac{1}{kT} ;$$
(81)

f (") is a Ferm i function.

Returning with the expression (78) to Eq. (75) we arrive at a new form of Landau expansion which is

$$F_{m} = F_{0} + m^{2} \frac{1 - K - F_{tot}^{F} I_{T}}{2I_{T}} + a_{4}m^{4} + \dots$$
 (82)

The critical (m in im um) value of the total Stoner eld creating ferrom agnetism; $(F_{tot}^{F})_{m in} = F_{tot}^{cr}$, is obtained from the zero of susceptibility denom inator (Eq. (78)) or zero of the num erator in Eq. (82), around which changes the sign of the second order term. Hence, we arrive at the well-known Stoner criterion (see [56,57])

$$F_{tot}^{cr} = \frac{1 K}{I_{T}} ; \qquad (83)$$

which is modied here by including the correlation factor K .

Using the Stoner condition $F_{tot}^{cr} = (1 \text{ K})/I_T$, back in the expression for susceptibility, Eq. (78), and in Landau expansion (82) we arrive at their corrected form s

$$= \frac{2 \frac{2}{B}}{F_{tot}^{cr} F_{tot}} ; \qquad (84)$$

$$F_m = F_0 + \frac{m^2}{2} (F_{tot}^{cr} F_{tot}) + a_4 m^4 + ...;$$
 (85)

since $a_4 > 0$, the existence of the minimum in the above equation for F_m will depend on the sign of $a_2 = \frac{1}{2} (F_{tot}^{cr} F_{tot})$ or equivalently on the sign of the dimense: $F_{tot}^{cr} F_{tot}$. As a result, the simple Stoner criterion (Eq. (83)) will lead to the ferrom agnetic instability with nonzero magnetic moment being given by the minimum of F_m curve in Fig. 2. This minimum appears only when existing in a given material, $F_{tot}^F > F_{tot}^{cr}$, the F_{tot}^{cr} being given by condition of Eq. (83). It is not mistake that in Eqs (84) and (85) we have F_{tot} without the upper-script F, since as we will see below those two equations are valid without any changes for both F and AF ordering.

To calculate the static antiferrom agnetic susceptibility we will apply Eq. (77) to the susceptibility of the sub-lattice $^{\rm 1}$

$$= {}_{B}^{0} \frac{2 n n}{2 (H)^{A}} {}_{H=0}^{A} ;$$
 (86)

and we will use expression (74) for the electron occupation on sub-lattice in the presence of an external eld, arriving at the following equation for the static antiferrom agnetic susceptibility

$$=\frac{2 \frac{2}{B} K_{x}}{1 K_{x} F_{tot}^{AF}}; \qquad (87)$$

where the correlation factor K $_{\rm x}$ in the antiferrom agnetic case can be written as

$$K_{x} = \frac{1}{2} \frac{@n}{@x} \frac{@n}{@x} = \frac{1}{2} \frac{?}{1} \frac{@(")}{@x} \frac{@(")}{@x} \frac{@(")}{@x} \frac{!}{!} \frac{d"}{1 + e^{(")/kT}} = \int_{1}^{2} \frac{@(")}{@x} f(") d":$$
(88)

Using the condition for the zero of susceptibility denom inator we arrive at the critical value of the total eld

$$F_{tot}^{cr} = \frac{1}{K_{x}(n)} \quad : \tag{89}$$

¹This susceptibility is a susceptibility of one sub-lattice. To nd its relation with the total experimental susceptibility one has to take into consideration the direction of the external eld with respect to the easy magnetic axis (see e.g. [58], [59])

A fter inserting this value into the sub-lattice susceptibility (Eq. (87)) and next to the form ula for Landau expansion (Eq. (75)) we obtain again the same form of the susceptibility as for ferrom agnetism (Eq. (84)), and of the free energy expansion as given by Eq. (85) for ferrom agnetism. Thus the susceptibility of Eq. (84) and the energy expansion of Eq. (85) are the same for F and AF. The di erence between these two orderings lies in the di erent values of critical (m inimum) eld. For F this eld is given by Eq. (83) and for AF by Eq. (89). In both cases when existing in a given m ateria $F_{tot}^{F(AF)} > F_{tot}^{cr}$, then the second order term in energy expansion vs. m agnetization becomes negative and we have a nonzero equilibrium value of the ordering param eterm, see Fig. 2.

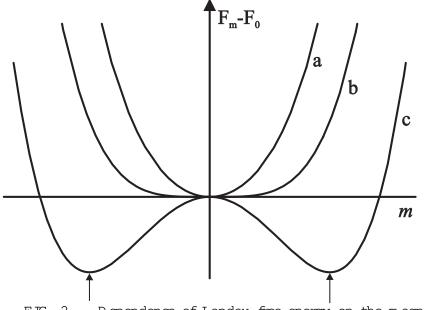


FIG.2. Dependence of Landau free energy on the magnetization m for various values of $a_2 = \frac{1}{2} F_{tot}^{cr} F_{tot}^{F(AF)}$. Curve (a) $-F_{tot}^{F(AF)} < F_{tot}^{cr}$, curve (b) $-F_{tot}^{F(AF)} = F_{tot}^{cr}$, curve (c) $-F_{tot}^{F(AF)} > F_{tot}^{cr}$.

4 FERROM AGNET ISM

4.1 ON SET OF FERROM AGNETISM

To compute the ferrom agnetic criterion from Eq. (83) we have to calculate the correlation factor, K, de ned in Eq. (79). We will calculate it now in the CPA approximation, assuming that we know the self-energy . The total change of the DOS with magnetization, K, which enhances the possibility of creating magnetic ordering, is given from Eq. (79) as

$$K = K_{\rm U} + K_{\rm b}$$
; (90)

where

$$K_{U} = 2 \int_{1}^{Z^{1}} \frac{@ (")}{@} \frac{@}{@m} f (")d"$$
(91)

and

$$K_{b} = 2 \int_{1}^{\frac{d}{2}} \frac{(")}{(b)} \frac{(b)}{(m)} f(") d" :$$
 (92)

Factor K $_{\rm U}\,$ describes the role of on-site interaction U , and K $_{\rm b}$ the role of inter-site interactions in creating m agnetization.

The schematic depiction of the DOS deformed by the on-site correlation U is shown in Fig. 3.

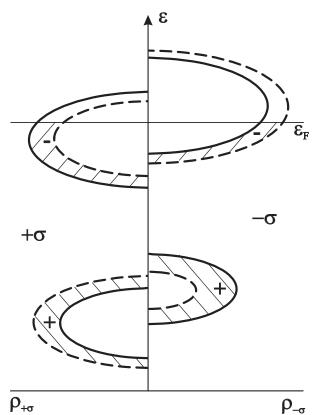


FIG.3. Schem atic DOS showing the in uence of the strong on-site C oulom b correlation, U. The param agnetic DOS for both spins, , are solid lines. At U which is strong enough to split the band into two sub-bands, lower sub-bands have the capacity of 1 n for + electrons, and 1 n for electrons. The changes in the spin electron densities integrated over energy are the shaded areas in this gure, and they are equal to the correlation factor K_U . The shift between + and electrons is created by the assumed exchange eld.

The schematic depiction of the DOS deformed by the inter-site correlation is shown in Fig. 4.

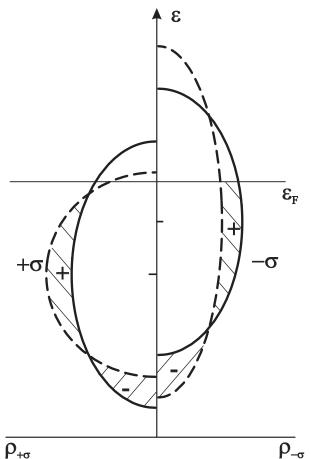


FIG.4. Schem atic DOS showing the in uence of the inter-site interactions. The param agnetic DOS for both spins, , are solid lines. The inter-site interactions change the relative width of the bands with respect to each other (described by the b factors, see Eq. (22)). The Stoner eld, which would displace the bands with respect to each other, is assumed to be nonzero. The shaded areas in this gure are the correlation factor K_b .

C om paring Figs 3 and 4 one can see that the on-site correlation causes an increase in capacity of the majority spin band (or lower sub-band in the case of split band), while the inter-site correlation causes a decrease in width of the majority spin band. There is an important di erence between these two elects. The situation from Fig. 3 can not lead by itself, without the exchange led, to ferrom agnetism (see [9,10]), while the majority spin bandwidth decrease (see Fig 4) can. However, there is the problem with the magnitude of the interaction constants, which can lead to this ordering. There is also a dilerence in the order of approximation necessary to obtain dilerent correlations. The band shape change shown in the Fig. 3 can be obtained only in the approximations higher than the 1st order in U=D, while the change shown in Fig. 4 is obtained already in the 1st order approximation (Hartree-Fock).

A fler inserting Eq. (90) into Eq. (78) one can write for the static ferrom agnetic susceptibility

$$= \frac{2 \frac{2}{B} I_{T}}{1 K_{U} K_{b} F_{tot}^{F} I_{T}}$$
(93)

At zero tem perature we obtain from Eq. (81) that; $I_T = {}^0 ("_F^0)/b^0$, where $"_F^0$ is the Ferm i level for the system without inter-site interactions and b^0 is the bandwidth change parameter in the paramagnetic state due to the inter-site interactions. This will modify the last relations into the following form

$$= \frac{2 \frac{2}{B} 0}{(1 - K_{U} - K_{b}) b^{0} F_{tot}^{F} 0} (\mathbf{m}_{F}^{0})$$
(94)

Comparing the above equation with the equation for susceptibility when there is only the Hartree-Fock exchange eld

$$= \frac{2 \frac{2}{B} 0 (\mathbf{W}_{\rm F}^{\rm 0})}{1 F_{\rm tot}^{\rm F} 0 (\mathbf{W}_{\rm F}^{\rm 0})}$$
(95)

one can see that the ferrom agnetic state will be favored by both positive correlation factors: K_U and K_b, and by a decrease in the bandwidth $b^0 < 1$ due to the inter-site interactions.

From the zero of the susceptibility denominator (Eq. (94)) and Eqs (80), (23), one can calculate the critical on-site exchange interaction.

$$F^{cr} = \frac{(1 K_{U} K_{b}) b^{0}}{({}^{\texttt{H}}_{F})} zJ 4D \frac{@}{@m} \frac{(1 S)^{2}}{2} I n I (1 S) ;$$
(96)

where the kinetic interactions were expressed by the common factor S, see Eq. (5).

The inter-site correlation factor given by Eq. (92) can be written as

$$K_{b} = 2 \int_{D}^{Z^{p}} (")P_{T} (") "\frac{@b}{@m} d":$$
(97)

At zero tem perature we have P_T (")) $\frac{(" "_F^0)}{b^0}$, which produces the following expression

$$K_{b} = -\frac{2 \frac{m_{F}^{0}}{F} \left(\frac{m_{F}^{0}}{h}\right)}{b^{0}} \frac{\partial b}{\partial m} \qquad : \qquad (98)$$

In further analysis we will use two limiting cases for the on-site C oulomb repulsion - weak and strong correlation.

In the case of weak correlation the C oulom b correlation factor $K_{U} = 0$, and the critical on-site exchange interaction depends only on the inter-site interactions through the inter-site correlation factor K_{b} . U sing I expressed by Eq. (13) one obtains

$$F^{cr} = \frac{(1 K_b)b^0}{{}^0(\mathbf{m}_F^0)} \quad zJ \quad 2D \quad \frac{(1 S)^2}{2}\frac{n^2}{4} + (1 S)(1 n) \quad ; \tag{99}$$

where the bandwidth change parameter in the paramagnetic state b^0 , is given by

$$b^{0} = 1 \quad (1 \quad S) n + (1 \quad S)^{2} \frac{4}{4} \frac{n^{2}}{4} \quad 3 \quad \frac{n(2 \quad n)}{4} \frac{{}^{2} \frac{3}{5}}{5} \quad \frac{2J + J^{0} \quad V}{t} \frac{n(2 \quad n)}{4} \quad : \quad (100)$$

To illustrate the dependence of the critical on-site Stoner eld, F cr on electron concentration (at zero tem perature) we will use the above equations and the initial sem i-elliptic DOS given by

$${}^{0} {}^{m^{0}} = \frac{2}{D} {}^{\frac{V}{U}} \frac{1}{1} \frac{{}^{m^{0}} \frac{1}{2}}{D} :$$
(101)

M athem atically this is the sim plest possible DOS which can be used for itinerant ferrom agnetism. The rectangular DOS does not have a unique relationship between the Stoner eld and the m agnetization, and the parabolic DOS does not take into account the inter-site interactions, since it does not have a nite width and is not centered on the atom ic level.

E lectron concentration in the param agnetic state (at T=0K) is calculated from the simple condition

$$\frac{n}{2} = \int_{D}^{Z_{F}^{0}} d\mathbf{u}^{0} ; \qquad (102)$$

with expression (101) inserted for the DOS. This will allow to calculate $"^0_F$ (n) and $"^0("^0_F)$ for a given electron occupation n. Finally, we calculate F^{cr} (n) from Eq. (99) with K b estimated from Eq. (98), with the help of the derivative $\frac{@b}{@m}$ calculated from Eq. (22).

Calculated in this way the dependence of critical on-site Stoner eld on electron concentration is shown in the Fig. 5 for the case of weak Coulomb correlation U and various parameters of inter-site interactionJ and S, at $J^0 = J$ and V = 0. Parameters S = 1 and J = 0 describe the classic Stonermodel.

We can see from this Figure that the decreasing factor S and increasing interaction, J, decrease the on-site Stoner eld required to create ferrom agnetism, even to zero, at some electron concentrations (solid line). Including only the inter-site exchange interaction (dashed line) lowers the critical eld symmetrically with respect to n = 1. The kinetic interactions: t_{ex} and t, described by the hopping inhibiting factor S < 1 (dotted line) lower the on-site Stoner eld, but now there is no symmetry with respect to the half-led point n = 1.

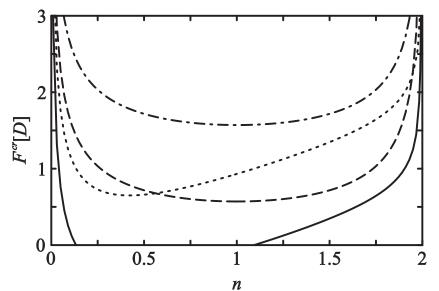


FIG.5. The dependence of the critical on-site Stoner eld, F^{cr} , on the electron occupation, for di erent values of S and J; S = 1 and J = 0 (the Stoner m odel) { dot-dashed line, S = 0:6 and J = 0:5t { solid line, S = 1 and J = 0:5t { dashed line, S = 0:6 and J = 0 { dotted line. This is the case of the weak C oulom b correlation, U.

In the case of strong correlation (U >> D) the band is split into two sub-bands. For the initial sem i-elliptic DOS given by Eq. (101) we obtain from Eq. (30) in this limit (see [10]) the following densities

- for the lower Hubbard sub-band

$$(") = \frac{2}{D_{ef}} \int_{ef}^{v} \frac{1}{1 n} \frac{u}{D_{ef}} ; \qquad (103)$$

- for the upper H ubbard sub-band

$$(") = \frac{2}{D_{ef}} \frac{\sqrt[v_u]{u}}{n} \frac{(")^{\frac{1}{2}}}{D_{ef}};$$
 (104)

щ

with " = " $^{0}b^{0}$, and $D_{ef} = Db^{0}$.

The parameter I is given by Eqs (16) and (17), which after inserting into Eq. (96) give the following values of the critical on-site exchange interaction

-for the lower H ubbard sub-band

$$F^{cr} = \frac{(1 \quad K_{U} \quad K_{b}) b^{0}}{{}^{0} ({}^{m_{E}^{0}})} \quad zJ \quad 2D \quad \frac{(1 \quad n)}{(2 \quad n)^{2}} \quad \frac{(1 \quad S)^{2}}{2} n^{2} + 4 (1 \quad S) (1 \quad n) \quad ; \quad (105)$$

-for the upper Hubbard sub-band

$$F^{cr} = \frac{(1 \quad K_{U} \quad K_{b}) b^{0}}{{}^{0} ({}^{\text{m}_{F}^{0}})} \quad zJ \quad 2D \quad (n \quad 1) \quad \frac{(1 \quad S)^{2}}{2} \quad 4 \quad (1 \quad S) \quad \frac{(n \quad 1)}{n^{2}}^{\#} ; \quad (106)$$

where ${}^{0}("_{F}) = \lim_{m \neq 0} (") = b^{0}$, with (") given by Eqs (103), (104) with n = n=2, and $"_{F}(n)$ calculated from Eq. (102) as $"_{F}(n) = "_{F}^{0}b^{0}$. The correlation factor K_{U} is calculated from Eq. (91), which at T = 0K is reduced to the simple condition

$$K_{U} = \int_{D_{ef}}^{\vec{Z}_{F}} \frac{\underline{\theta}(\mathbf{''})}{\underline{\theta}_{m}} d\mathbf{''} = 2 \int_{D_{ef}}^{\vec{Z}_{F}} \frac{\underline{\theta}(\mathbf{''})}{\underline{\theta}_{m}} d\mathbf{''} = 2 \int_{D_{ef}}^{\vec{Z}_{F}} \frac{\underline{\theta}(\mathbf{''})}{\underline{\theta}_{m}} d\mathbf{''} ; \qquad (107)$$

in which we will use the DOS given by Eqs (103) and (104).

We calculate $F^{cr}(n)$ from Eq. (106), with K_b given by Eq. (98). The bandwidth b^0 is calculated from Eq. (22) with I given by the m = 0 lim it of Eqs (20) and (21), for the lower and upper sub-band, respectively.

Fig. 6 shows that in the presence of the on-site strong correlation U, the inter-site interactions: J; S, decrease the critical Stoner eld dram atically. The increase of J causes the decrease of F^{cr} for concentrations nearly half-led and also at sm all concentrations and concentrations close to completely led. The decrease of S from 1 to 0 causes a drop of the critical Stoner eld, F^{cr}, especially for sm all n < 0.5, and for 1 < n < 1.5, where both Hubbard sub-bands begin to ll. A swe know the strong C culom b repulsion causes the split of the band. This split causes the change in sign of the inter-site correlation factor K_b when the Ferm i level m oves from the lower to the upper Hubbard sub-band. For S \notin 1 the ratio $\frac{K_{\rm B}b^0}{0 \, {\rm (m_F^{\circ})}} \notin$ 0. This is why the curves with S < 1w ill have a discontinuity at half lling, when the Ferm i level j jm ps from the lower to the upper sub-band.

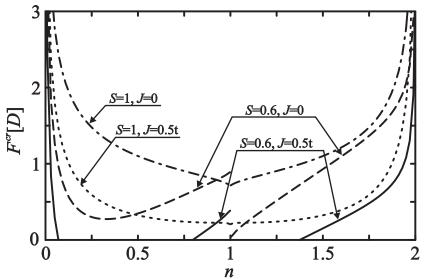


FIG.6. Dependence of the on-site critical Stoner eld, F^{cr} (in the units of half bandwidth), on the electron occupation. The curves show the in uence of inter-site interactions, $J = J^0$, V = 0, and of the hopping interactions, $t; t_{ex}$, represented by the hopping 'inhibiting' factor S on F^{cr} in the presence of strong on-site correlation, U = 1.

To justify the use in this chapter of the rather academ ic lim it of U >> D for F ordering we compare on the next graph the three cases; U = 0, U = 3D, and U >> D. All the curves

were calculated on the base of Eqs (101), (30) and (102). One can see that the di erence between the curves U = 3D, and U >> D is small. This justiles the use in numerical calculations (for simplicity) of the strong correlation limit U >> D.

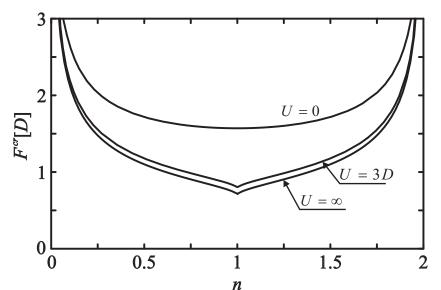


FIG.7. Dependence of the on-site critical Stoner eld, F^{cr} (in the units of half bandwidth), on the electron occupation, which shows the in uence of on-site correlation, U. The inter-site interactions are zero (J = 0; S = 1)

Enhancem ent of magnetic susceptibility

The susceptibility given by Eq. (93) for $T \in 0$ K or Eq. (94) for T = 0 K is not divergent for most of the pure elements, as only few of them are magnetic. But for many pure elements the denom inator of susceptibility is significantly decreased, which produces the experimentally observed increase of susceptibility. This phenomenon was extensively studied in the past. From Eq. (94) in the H-F approximation for U, and in the absence of the inter-site interactions, when $K_{\rm U} = 0$, $K_{\rm b} = 0$, and $b^0 = 1$ (see e.g. [57]) one can write

$$= \frac{2 \frac{2}{B} 0}{1 - F_{tot}^{F} 0} (\mathbf{n}_{F}^{0}) = P_{P} A ; \qquad (108)$$

where the bare Pauliterm $_{\rm P} = 2 \frac{2}{B} \frac{0}{6} (\mathbf{W}_{\rm F}^0)$ is enhanced by the factor $A = 1 \frac{1}{1} \frac{1}{F_{\rm tot}^{\rm F}} \frac{1}{F_{\rm tot}^{\rm F}}$ the Stoner enhancem ent factor. This enhancem ent in the case of nonzero correlations is given by

$$A = 1 (1 K_{U} K_{b}) b^{0} F_{tot}^{F} (\P_{F}^{0})^{i}$$
(109)

In the past the CPA approximation describing the on-site repulsion $U; K_U \in 0, b^0 = 1$, was used to calculate this enhancement (see [9] for the general model of pure elements and e.g. [60{62] for susceptibility of disordered binary alloys). Experimental data and theoretical results from the local density functional method were collected more recently for pure

transition elements by [56]. In this chapter the factor A (Eq. (109)) is additionally increased by the inter-site interactions; $K_b \in 0$, $b^0 < 1$. This e ect should be also included in the investigation of experimental data on the susceptibility enhancement.

4.2 NUMERICAL RESULTS FOR MAGNETIZATION AND CURIE TEM - PERATURE

The Curie tem perature, at which magnetization vanishes, is calculated from the zero of the susceptibility denominator, Eq. (93), attained with tem perature

$$1 K_{\rm U} K_{\rm b} F_{\rm tot}^{\rm F} I_{\rm T} = 0 \quad : \tag{110}$$

Quantity F_{tot}^{F} calculated from this equation at nonzero temperature is larger than F_{tot}^{cr} , calculated from the same equation (110) at zero temperature, since I_{T} has its maximum $I_{T} = {}^{0} (\P_{F}^{0})/b^{0}$ at zero temperature.

In the case of weak C oulom b correlation (U = 0) the C oulom b correlation factor, $K_{\rm U} = 0$, hence the C urie temperature depends only on $K_{\rm b}$ and $I_{\rm T}$.

In the case of strong C ou lom b correlation (U >> D) according to Eq. (110) we have to include the correlation factor K_U given by Eq. (91). In this case the band is split into two sub-bands. U sing the DOS given by Eqs (103) and (104) we calculate num erically the correlation factor K_U from Eq. (107) where the self-energy was elim inated

$$K_{U} = 2 \int_{1}^{\frac{1}{2}} \frac{0}{0} (") d" : \qquad (111)$$

A lternatively, we can calculate directly the magnetization as; m(T) = n , with n from Eq. (36) for a given electron occupation; n = n + n, and then obtain the Curie temperature by searching for the Curie point where (T_c) ! 0.

The procedure for calculations is the following. We use Eq. (37) for the electron occupation number, which corresponds to a given 3d ferror agnetic element in the Table I. We adjust the value of total Stoner eld, F_{tot}^{F} , to create the experimental zero temperature magnetization m (T ! 0 K) = n (0 K) n (0 K). Having obtained F_{tot}^{F} we calculate the on-site Stoner eld, F, from Eq. (26) at the given assumed inter-site interactions J, S and D = 3d halfband-width according to [63].

Next, we calculate the Curie temperature with the same constants, F, J and S using Eq. (38) for the magnetization and searching for the point where m (T_c) ! 0.

The results in acase of the weak correlation are collected in the Table I.

TABLES

Modied Stoner Modelwith U = U								
E lem ent	n	m	D [eV]	T _c [K] F(m)[eV]	No.5			
			t[eV]	No.1	No2	No3	No.4	T _c ^{exp} [K]
				S = 0 : 6	S = 0 : 6	S = 1	S = 1	
				J = 0:5t	J = 0	J = 0:5t	J 0	
Fe	1.4	0.44	2.8	2050	3295	3980	4290	1043
			0.35	1.18	3.76	2.28	4.85	
Со	1.65	0.344	2.65	1690	3300	3880	4710	1388
			0.22	1.86	4.46	3.0	5.6	
Ni	1.87	0.122	2.35	620	870	1720	1960	627
			0.20	2.33	4.72	4.0	6.4	

TABLE I. Curie Tem peratures and Values of 0 n-site Stoner Field for Ferrom agnetic E lem ents, M odi ed Stoner M odel with U = 0

It is very interesting to compare the di erent results for T_c which are shown in this Table. C olum n no. 4, which is the Stoner m odel for sem i-elliptic D O S, shows that all theoretical results of the pure Stoner m odel are m uch higher than the experim ental C urie tem peratures (colum n no. 5). This means that the Stoner m odel, which assumes that the on-site atom ic eld creates ferrom agnetism, overestim ates, to a large extent, the C urie tem perature. The necessary on-site Stoner eld is also unrealistically high. Perhaps ferrom agnetism is the result of inter-site forces changing the bandwidth, since colum n no. 1 is closest to the experimental results. The larger the component of the on-site eld (i.e. S ! 1, J ! 0), the more the T_c results exceed the experimental values. However, one has to be careful not to overestim ate these inter-site interactions since they suppose to be weak. They lower substantially the Curie tem perature, but the remaining di erence between theoretical and experimental values is still signi cant and it has to be attributed to the therm al spin uctuations, since there is an experimental evidence of such uctuations (see [56,64])

These simple calculations would con m the earlier attempts of understanding the itinerant ferrom agnetism as the e ect of ordering local m om ents, whose alignment disappear at the Curie temperature. However, the moments them selves exist up to the temperatures exceeding the Curie temperature by two or three times (see M izia [65]). We could think about local moments as being created by the Stoner on-site eld, but their ordering would be driven by the inter-site interactions, which is much weaker than the on-site eld.

In the case of strong correlation the procedure of calculations is the same as in the case of the weak correlation. First, we adjust the on-site exchange interaction F (at given inter-site parameters J;S) to the magnetic moment at zero temperature. We use the DOS given by Eqs (103) and (104). The correlation factor is calculated from Eq. (111). Finally, we calculate the Curie temperature from Eq. (110), or from the condition of vanishing magnetization, with the same interactions F;J and S.

Table II shows the results of C unie tem peratures obtained for the strong on-site correlation from the Stoner model (S = 1;J = 0), and for the cases with nonzero kinetic and exchange inter-site interactions. It can be seen that the in uence of strong on-site correlation (U = 1) does not lower the theoretical C unie tem perature when compared to the case of no on-site correlation (U = 0) (see Table I), although the necessary on-site exchange eld, F, in the case of strong on-site correlation (U = 1) is lower than without it, U = 0 (compare Figs 5 i 6).

E lem ent	n	m	T _c [K] F (m) [eV]	T _c ^{exp} [K]			
			S = 0 : 6	S = 0 : 6	S = 1	S = 1	
			J = 0 : 5t	J = 0	J = 0 : 5t	J = 0	
Fe	1.4	0.44	2420	4000	3810	4960	1043
			0.41	2.45	1.03	3.06	
Со	1.65	0.344	1850	3270	3990	5180	1388
			1.35	3.65	1.82	4.12	
Ni	1.87	0.122	630	910	1770	2020	627
			1.94	4.2	2.9	5.16	

TABLE II. Curie Tem peratures and Values of On-site Stoner Field for Ferrom agnetic 3d E lem ents, M odi ed Stoner M odel with U = 1

Now we want to focus on the temperature dependence of the magnetization m which is plotted in Fig. 8. The dependence m (T) was calculated for the strong correlation and without the correlation for electron occupation representing iron. In both cases we assumed; J = 0, S = 1 and J = 0.5t, S = 0.6.

O ne can see from this gure that the strong on-site correlation U is not helping ferrom agnetism at all, as the curves with U >> D lay above the corresponding curves with U = 0.

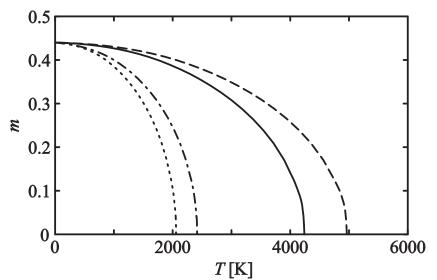


FIG.8. M agnetization dependence on temperature, m (T), without and with strong C oulom b correlation, n = 1:4, D = 2:8 eV for di erent values of param eters J and S; U = 0, J = 0, S = 1-solid line, U = 1, J = 0, S = 1-dashed line, U = 0, J = 0.5t, S = 0:6-dotted line, U = 1, J = 0.5t, S = 0:6-dotted line.

5 ANTIFERROM AGNETISM

5.1 ON SET OF ANT IFERROM AGNET ISM

W e can nd the critical value of the total eld creating AF from Eq. (89) using for K $_{\rm x}$ the expression (88)

$$K_{x} = \frac{\overset{R}{}}{_{0x}} \frac{\overset{(")}{}}{_{0x}} f(") d" = \overset{\overset{R}{}}{_{0x}} \frac{\overset{(")}{}}{_{0}} f(") d"$$
$$= \frac{1}{\overset{R}{}} \frac{\overset{(")}{}}{_{k}} f(") \frac{1}{\overset{1}{}} \operatorname{Im} \frac{\overset{h^{1}}{_{0}} \frac{\overset{(")}{}}{_{0}} \frac{i}{_{0}}}{\overset{(")}{_{0}} \frac{i}{_{0}}} d"$$
(112)

Dierentiating Eq. (64) we can show that

$$\frac{@G (";k)}{@}_{!0} = \frac{1}{"+"_{k}} \frac{1}{""_{k}} \frac{1}{2"_{k}} :$$
(113)

U sing this expression in Eq. (112) we obtain the follow ing form ula

$$K_{x} = \frac{1}{N} \frac{X}{k} \frac{f(\mathbf{"}_{k}) - f(-\mathbf{"}_{k})}{2\mathbf{"}_{k}} = \frac{1}{N} \frac{X}{k} \frac{1}{4\mathbf{"}_{k}} \tanh \frac{1}{2} (\mathbf{"}_{k}) - \tanh \frac{1}{2} (-\mathbf{"}_{k}) + \frac{1}{2$$

We can calculate now F_{tot}^{cr} (n) from the relation; $F_{tot}^{cr} = 1 = K_x$. The above equation although sim ilar to the condition for superconductivity is di erent in two respects (see [66]). First, the summation runs from k minimum in the band to maximum k, giving a positive K_x and positive F_{tot}^{cr} (n). Second, in the denominator we have the dispersion relation "_k, which is centered on the average energy of the band not around the chem ical potential, like in the case of superconductivity (see [67]).

From the expression for the electron numbers n (= ;) (Eq. (70)) we obtain in the mean-eld approximation that the antiferrom agnetic moment per atom (in Bohr's m agnetons) is given by the following expression

$$m = n \quad n = \frac{1}{2N} \sum_{k}^{X} P_{k}^{+} P_{k} \quad [f(E_{k}) \quad f(E_{k})] :$$
 (115)

The chemical potential is determined from the carrier concentration non the basis of the equation, which also comes from Eq. (70)

$$n = n + n = \frac{1}{2N} \sum_{k}^{X} P_{k}^{+} + P_{k} \quad [f(E_{k}) + f(E_{k})] :$$
(116)

Inserting Eq. (72) into Eq. (115) and using the relation (74) we obtain

$$1 = F_{tot}^{AF} \frac{1}{N} \frac{X}{E_{k}} \frac{1}{2E_{k}} [f(E_{k}) - f(E_{k})] : \qquad (117)$$

щ

At the transition from AF to norm alstate; ! 0, and the condition (117) takes on the form

$$1 = F_{tot}^{cr} \frac{1}{N} \frac{X}{k} \frac{f("_{k}) - f(-"_{k})}{2"_{k}} = F_{tot}^{cr} \frac{1}{N} \frac{X}{k} \frac{1}{4"_{k}} \tanh \frac{1}{2} ("_{k}) + \tanh \frac{1}{2} (-"_{k})$$
(118)

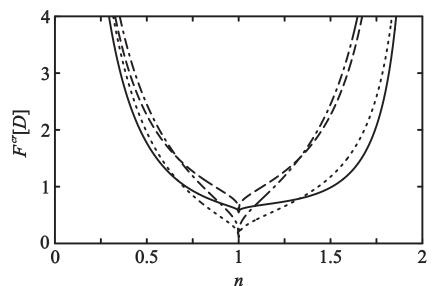
where $\mathbf{w}_{k} = \mathbf{w}_{k}^{0} \mathbf{b}^{AF}$, which is the same as the result (114) coming from the static magnetic susceptibility.

For the num erical analysis we will use the ! 0 lim it of Eq. (116) and of Eq. (118) in their integral form ,

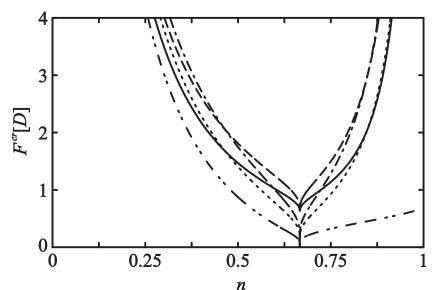
$$n = 2 \qquad (") f (")d" ; \qquad (119)$$

$$1 = F_{tot}^{cr} \begin{pmatrix} {}^{D}R^{ff} \\ {}^{D}e^{ff} \end{pmatrix} \begin{pmatrix} {}^{H} \end{pmatrix} \begin{pmatrix} {}^{f} \end{pmatrix} \begin{pmatrix} {}^{I} \end{pmatrix} \begin{pmatrix} {}^{f} \end{pmatrix} \begin{pmatrix} {}^{I} \end{pmatrix} \begin{pmatrix} {}$$

and the sem i-elliptic DOS given by Eq. (101) in the case of the weak Coulom b correlation U. For the strong Coulomb correlation U we will use split densities given by Eqs (103) and (104). The results will show how the critical on-site exchange eld depends on the electron concentration. Figs 9 and 10 show the dependence of this interaction, F^{cr}, on the electron concentration for di erent values of the inter-site and kinetic interactions, described by the parameters; J, S, in the case of weak and strong Coulom b correlation U. A nalyzing these curves one can see that the inter-site exchange interaction J increases values of onsite exchange interaction, F^{cr}, required for AF. The decrease in F^{cr} can be achieved when J < 0. This e ect is opposite to the case of ferrom agnetism, where stabilization of ordering was obtained for J > 0. Those two di erent e ects of inter-site exchange interaction on m agnetism can be roughly understood when one com pares the expressions for total eld in the case of ferrom agnetism ; $F_{tot}^{F} = F + z [J + t_{ex} \frac{n^2 m^2}{2} + 2 t(1 n)]$, and antiferrom agnetism $F_{tot}^{AF} = F \quad z (J + 2t_{ex} I_{AF})$. We use the word Youghly' since in calculating the critical elds there is included also the factor of the band-width change, which does not appear in the elds. The result of this simplied approach with respect to the inter-site exchange energy, J_{4} is in agreem ent with the H eisenberg term for the interaction energy of localized spins; $J \subseteq S_i$, which points towards ferrom agnetism when J > 0, and towards antiferrom agnetism when J < 0. A nalyzing the in uence of inter-site interaction J on long range ordering one has to remember that the negative value of this interaction stimulates the d-wave superconductivity (see e.g. [68]). As a result it will cause the co-existence of SC and AF ordering. This is why the t-J m odel was successful in describing co-existence of the singlet SC and antiferrom agnetism . A lthough one has to rem ember that this model has a contradiction in its very origin. This contradiction lies in considering electrons as itinerant (the kinetic t-term) and localized (the potential J-term) at the same time. Including in our model the kinetic interactions; t and t_{ex}, has decreased the minimum on-site exchange interaction necessary for AF. The hopping interaction t decreases F^{cr} by decreasing the band-width (see [69]). Positive exchange-hopping interaction t_{ex} also decreases the bandwidth but at the same time it decreases the elective eld (see above or Eq. (62)). In elect the in uence of this interaction on AF is very small.



nFIG.9. The dependence of the critical on-site exchange, F^{cr} , on the electron occupation, The case of the weak correlation U. The curves for di erent values of S and J are; S = 1 and J = 0{ dot-dashed line, S = 0:6 and J = 0:5t { solid line, S = 1 and J = 0:5t { dashed line, S = 0:6 and J = 0:6 and J = 0.5t { solid line, S = 1 and J = 0:5t { dashed line, S = 0:6 and J = 0:6 and J = 0.5t { dotted line.



nFIG.10. he dependence of the critical on-site exchange, F^{cr}, on the electron occupation. The case of the strong correlation U. The curves for di erent values of S and J are; S = 1 and J = 0{ dot-dashed line, S = 0.6 and J = 0.5t { solid line, S = 1 and J = 0.5t { dashed line, S = 0.6 and J = 0 { dotted line. The double dotted-dashed line is for t = t (t₁ = 0 or S = 0), and t_{ex} 0 (see Eq. (125) below).

Including into calculations the inter-site interactions; $J; J^0; V$, does not shift them in imum of the critical eld F^{cr}(n), which for the weak correlation is located at n = 1, and for the

strong correlation at n = 2=3. The inter-site interactions do not change the character of the critical curves, they only lower them by a factor of b^{AF} from Eq. (39) or (40). Remembering that $" = "^0 b^{AF}$ this can be proved analytically

$$K_{x}(n) = \prod_{\substack{D_{eff} \\ D_{eff}}}^{D_{eff}} (\mathbf{''}) \frac{f(\mathbf{''}) f(\mathbf{''})}{2\mathbf{''}} d\mathbf{''}$$

$$= \frac{1}{b^{A_{F}}} \bigwedge_{D}^{R} (\mathbf{''}^{0}) \frac{f(\mathbf{''}^{0} b^{A_{F}}) f(\mathbf{''}^{0} b^{A_{F}})}{2\mathbf{''}^{0}} d\mathbf{''}^{0} = \frac{1}{b^{A_{F}}} K_{x}^{0}(n)$$
(121)

Since $F_{tot}^{cr} = 1=K_x$, and $F_0^{cr} = 1=K_x^0$ we obtain that

$$\mathbf{F}_{\text{tot}}^{\text{cr}} = \mathbf{F}^{\text{cr}} \quad \mathbf{z} \left(\mathbf{J} + 2\mathbf{t}_{\text{ex}} \mathbf{I}_{\text{AF}} \right) = \mathbf{b}^{\text{AF}} \mathbf{F}_{0}^{\text{cr}} \quad ; \tag{122}$$

where F^{cr} and F_0^{cr} are the critical on-site exchange elds for A F with and without the intersite interactions, respectively.

Including the kinetic interactions, S < 1, leaves the m inim a of critical curves where they are as it only changes the factor b^{AF} in Eq. (122). In this chapter we assumed dependence of the hopping energy on the occupation expressed by the equation

$$t_{ij} = t t(\hat{n}_{i} + \hat{n}_{j}) + 2t_{ex}\hat{n}_{i} \hat{n}_{j}$$
 (123)

This relation together with the other inter-site interactions; $J; J^{0}; V$, expressed in the generalized Hartree-Fock approximation brought the Eq. (39) for b^{AF} with I_{AF} given by Eq. (20) or (21) in the case of U >> D. The only exception from the scaling rule for critical on-site exchange interaction in the case of U >> D is the situation when b^{AF} (n = 1) = 0. This would cause the critical curve to drop at n = 1, what would make antiferrom agnetism possible at this concentration. In the itinerant band model this is the situation when there is localization at half-lling. As a result we obtain at this concentration possible AF, and since the band will expand very rapidly with the occupation n departing from one there will be also a strong driving force towards SC (see [70]). In such circum stances we will have the co-existence or rather competition at n = 1 between AF and $SC \cdot U$ nfortunately, since I_{AF} (n = 1) = 0, the relation (39) gives b^{AF} (n = 1) \in 0. In our previous paper (see [69]) we have the zero bandwidth at n = 1, but we have neglected the t_{ex} term in Eq. (3) or (123) above. This is equivalent to the use of H irsch's sim pli ed linear approach (see [47,71])

$$t_{ij} = t t(\hat{n}_{i} + \hat{n}_{j});$$
 (124)

instead of Eq. (123). From this relation it follows that

$$b^{AF} = 1 - \frac{t}{t}n - \frac{2J + J^0 - V}{t}I_{AF}$$
 : (125)

At $t = t \text{ or } t_1 = 0$ this equation gives b^{AF} (n = 1) = 0, and we have the possibility of AF ordering, see the double dotted-dashed line in Fig. 10. AF can occur at n = 1 only when t_1 0 what means that there is no hopping in the presence of other electrons with opposite spin, and additionally when t_{ex} 0, which leads to the strange condition that $t_2 = t$. A lternatively we can obtain the Eq. (124) (which leads to the AF at n = 1) from

the basic Eq. (2) in a rst approximation by neglecting all the operator products of the type; \hat{n}_i \hat{n}_j in Eq. (2).

5.2 NUM ERICAL RESULTS FOR MAGNETIZATION AND NEEL'S TEM - PERATURE

The analysis of Eqs (116) and (117) in their integral form will give the magnetization dependence on the temperature for di erent values of the on-site and inter-site interactions.

$$n = (") [f(E) + f(E)]d";$$
(126)

$$1 = F_{AF} \qquad (") \frac{[f(E) f(E)]}{2E} d" ; \qquad (127)$$

where

$$E = {}^{p} {}^{m^{2} + 2} ; = F {}^{AF} {}^{m} {}_{tot} {}^{2} ; F {}^{AF} {}_{tot} {}^{F} {$$

From the above equations we nd numerically the sub-lattice magnetization, and the N eel's temperature, which is the temperature where this magnetization drops to zero. Fig. 11 presents the dependence of N eel's temperature, T_N , on electron concentration for di erent values of the inter-site and kinetic interactions for the weak C ou lom b correlation. A little curves are for the same on-site exchange eld. The curves with nonzero inter-site exchange interaction J have a low erN eel's temperature, because this interaction decreases the elective exchange interaction; F_{tot}^{AF} , $F_{tot}^{AF} = F = z (J + 2t_{ex}I_{AF})$. This elect is stronger than the decrease of the bandwidth due to J (see Eq. (39)), which increases T_N . The assisted hopping interaction t = t(1 - S), and kinetic-exchange interaction $t_{ex} = \frac{t}{2} (1 - S)^2$ increase the N eel tem perature by decreasing the bandwidth (Eq. (39)).

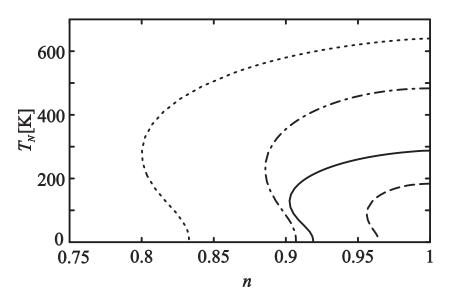


FIG.11. Dependence of the N œl's tem perature (T_N) on electron concentration for D = 0.5 eV, F = 0.34 eV and for di erent values of S and J in the case of the weak C oulom b correlation; S = 1 and J = 0 { dot-dashed line, S = 0.7 and J = 0.2t { solid line, S = 1 and J = 0.2t { dashed line, S = 0.7 and J = 0 { dotted line.

Figure 12 shows the magnetization versus temperature for electron occupation n = 0.95and for various values of the inter-site and kinetic interactions. Again, all the curves are calculated for the same internal exchange eld F = 0.34 eV. Similarly to the calculations of N celtern perature (in Fig. 11) at constant value of the on-site exchange eld, the highest magnetization is obtained for parameter S < 1, which means that magnetization is enhanced when electron hopping is inhibited in the presence of other electrons.

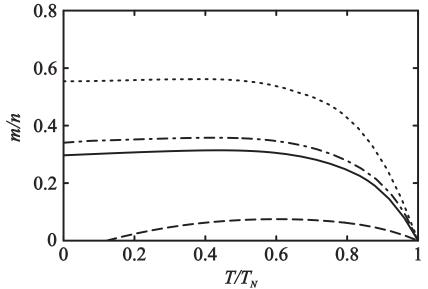


FIG.12. M agnetization versus tem perature for band lling n = 0.96, D = 0.5 eV, F = 0.34 eV and for di erent values of S and J; S = 1 and J = 0 { dot-dashed line, S = 0.7 and J = 0.2t { solid line, S = 1 and J = 0.2t { dashed line, S = 0.7 and J = 0.2t { dashed line, S = 0.7 and J = 0.2t { dashed line, S = 0.7 and J = 0.85 eV.

TABLE III. N eel's Tem peratures and Values of On-site Stoner Field for Antiferrom agnetic E lem ents, U = 0

Element n m D	[eV]	T _N [K] F ^{AF} (m) [eV]	No.5
---------------	-------	--	------

				Nol	No2	No.3	No.4	T _N ^{exp} [K]
				S = 0 : 6	S = 0 : 6	S = 1	S = 1	
				J = 0 : 5t	J = 0	J = 0:5t	J 0	
Cr	1.08	80.0	3.5	520	1430	1530	2440	311 [72]
				2.37	1.47	3.17	2.27	
Мп	1.24	0.48	2.8	2110	5840	7090	10820	540 [56]
				2.41	2.65	4.47	4.71	

Table III shows the N eel's tem perature calculated for the 3d antiferrom agnetic elements (C r and M n) in the case of the weak correlation. F inst the on-site exchange interaction, F, at a given assumed inter-site interactions J and S; was found from Eq. (43) after thing F_{tot}^{AF} to the experimental magneticm on ent at T = 0. Next, using the same F the Neel's tem perature was calculated. The results show that the inter-site, J, and kinetic, S, interactions decreased the Neel's tem perature (colum n no. 1). The difference between experimental and theoretical Neel's temperature is even larger than in the case of ferror agnetism (confer Table I). The large difference has to be attributed, as in the case of F, to the spin waves or spin uctuations (see [56,64,72]).

6. CONCLUSION

W e will sum m arize now the results for ferrom agnetism and antiferrom agnetism obtained in this article. Our analysis of the Hubbard model was focused on the in uence of the on-site and inter-site C oulom b correlation and the kinetic interactions on m agnetism. W e analyzed m agnetic susceptibility, the values of critical exchange interaction, the transition tem perature and the m agnetization.

In analyzing the ferrom agnetic ordering we have found three driving forces contributing to this ordering.

(i) spin dependent band shift (Stoner shift) coming from the on-site F and inter-site exchange interactions J,V and the kinetic interactions t,t $_{\rm ex}$ (represented by the parameter S),

(ii) spin dependent change of the band width and band capacity depending on the electron concentrations due to the on-site Coulomb repulsion described by the on-site correlation factor K $_{\rm U}$. Increased capacity of the majority spin sub-band drives the magnetism .

(iii) spin dependent change of the band width and band shape depending on the electron concentrations due to the inter-site interactions described by the inter-site correlation factor K $_{\rm b}$. N arrow ing of the m a jority spin sub-band drives the m agnetism .

The rst e ect is the classic e ect known since the approach of W eiss [73] and Slater [74] to magnetism. This is lowering of the potential exchange energy during the transition from the param agnetic to ferrom agnetic state. During this transition there is an increase in the kinetic energy. The balance of the sum of these two energies decides whether the actual transition takes place. This balance leads to the existence of the critical values for di erent interactions, above which the transition takes place. In its original form it gives us the Stoner condition for ferrom agnetism; F_{cr}^{F} ("_F) > 1. In the new development, described in points two and three above, the increase in the kinetic energy is moderated by the on-site and inter-site correlation e ects. These correlations will also change (decrease) di erent critical interactions coming from the total energy balance. The inter-site and on-site correlations are com ing into the critical condition throughout the correlation factors, which appear in the denominator of the susceptibility (Eq. (84)) and as the coe cient of second order term in the free energy expansion over magnetization (Eq. (85)), which is proportional to the inverse of susceptibility. The inter-site and on-site correlations reduce signi cantly the denom inator of the static magnetic susceptibility (Eq. (84)). For this reason the magnetic susceptibility is enhanced for the m aterials with strong electron correlation (Eq. (109)). The zeros of the

denom inator give the critical values of the total interaction, which is greatly reduced with respect to the classic Stoner model.

A nalysis of the inter-site correlation has shown the great decrease of the Curie tem perature towards the experimental values (see Table I i II). First, the direct calculations within the original Stoner model (see Section 4.2) have pointed out that the Curie tem perature, after thing the Stoner shift to the experimental magnetic moment at zero tem perature, is much too high (see Table I). Next, using the modi ed H-F approximation for the inter-site interactions, which is equivalent to introducing the inter-site correlation in the rst order approximation, we arrived at much lower Curie tem peratures. Considering the simplicity of the model, and the additional presence of spin waves which are out of the scope of this chapter, the results were close enough to the experimental data (see Table I). Apparently the inter-site interactions are 'softer' and decrease faster with the tem perature than the on-site Stoner eld used in the original Stoner model (see also [75]). Adding up the on-site strong correlation U to the Stoner model do not im prove the values of the theoretical Curie tem perature (see Table II). This fact can be understood better after exam ining Fig. 6 and Fig. 7, where the critical eld (initializing magnetization) has dropped down at half-lling but not at the end of the band, where the 3d elements are located.

As already established in the past the electron on-site correlation can help in creating antiferrom agnetism (AF) at half-led band, where the antiferrom agnetic 3d elements (Cr, Mn) are located, by dropping the critical eld for AF to zero (see Fig. 9) in the case of the weak on-site correlation. The strong U, which gives the correct results for the cohesion energy in the middle of the 3d row (see [63,76,77]), shifts the zeros of the critical eld for AF to the maxim a of the two split sub-bands, which are located at n = 2=3, and n = 4=3 (see Fig. 10). Unfortunately, this does not agree with the experimental evidence for AF, which is present around n = 1. The introduction of inter-site interactions in the modi ed H-F approximation does not shift these minima. It only lowers the critical curves (see Fig. 10). The inter-site interactions (J;J⁰;V) do not reduce the bandwidth at n = 1 (which would lower the critical curves at this concentration), in the case of the strong C oulom b correlation, since I_{AF} (n = 1) = 0 (see Eqs (20) and (21)).

There is one exception to this rule. We can obtain AF at half-lling at large U if the bandwidth at n = 1 goes to zero. This can be achieved in the linear approximation, which was described in x5.1. The bandwidth was reduced to zero by assuming that the hopping integral in the presence of another electron is forbidden at concentration n = 1; $t_1 = 0$, and additionally that t_{ex} 0 (see Eq. (125)).

In conclusion the antiferrom agnetism at half-lling in the high correlation case can appear when the bandwidth goes to zero at this concentration. It can go to zero either as: $1 n \frac{t}{t_0}$, due to the presence of the assisted hopping interaction or due to some other interaction, whose strength is proportional to n.

This situation can describe the high temperature superconducting cuprate YBaCuO, where at the half-lling and the strong Coulomb correlation there is, initially, the antiferrom agnetic order. The superconductivity will appear upon doping only away from the half-lling at the electron concentration n 0.95 0.8 (see e.g. [78]).

The tem perature dependence of AF was analyzed num erically in Section 52. Again, as in the case of ferrom agnetism the direct calculations within the original Stoner m odel have pointed out that the N œl's tem perature, after thing the Stoner shift to the experimental

m agnetic m om ent at zero tem perature, is m uch too high (see Table III). N ext, using the m odi ed H-F approximation for the inter-site interaction, we arrived at much lower Curie tem peratures. They are not as close to the experimental data as in the case of ferrom agnetism. The reason for this could be the existence of non linear modes of excitations in Chrom ium and M agnesium (see e.g. [72]). N evertheless, as already mentioned above, the model is very simple, the details of the realistic D O S as well as the magnetization decrease through the spin waves excitation or moment uctuations could be included, which would bring the theoretical results to complete agreement with the experimental data.

REFERENCES

[1] Hubbard J. Proc. R. Soc. A 1963, 276, 238. [2] Gutzwiller M C Phys. Rev. Lett. 1963, 10, 159. [3] K anam ori J. Prog. Theor. Phys. 1963, 30, 275. [4] Stoner E.C. Proc. Roy. Soc. A 1936, 154, 656. [5] Stoner E.C. Proc. Roy. Soc. A 1938, 165, 372. [6] W ohlfarth E P. Philos. M ag. 1951, 42, 374. [7] Hubbard J. Proc. Roy. Soc. 1964, A 281, 401. [8] Velicky B ; K inkpatrick S ; Ehrenreich H . Phys. Rev. 1968, 175, 747. [9] Fukuyam a H.; Ehrenreich H. Phys. Rev. B 1973, 7, 3266. [10] M izia J. phys. stat. sol. (b) 1976, 74, 461. [11] Nolting W ; Borgie W . Phys. Rev. B 1989, 39, 6962. [12] Herrm ann T.; Nolting W.J.Magn.Magn.Mater. 1997, 170, 253. [13] Herrm ann T.; Nolting W. Phys. Rev. B 1996, 53, 10579. [14] Hirsch JE. Phys. Rev. B 1985, 31, 4403. [15] Pruschke T ; Jarrell M ; Freericks J K . Adv. Phys. 1995, 44, 187. [16] Georges A ; Kotliar G ; K rauth W ; Rozenberg M J. Rev. Mod. Phys. 1996, 68, 13. [17] Metzner W ; Vollhardt D. Phys. Rev. Lett. 1989, 62, 324. [18] Blankenbecler R.; Scalapino D.J.; Sugar R.L. Phys. Rev. D 1981, 24, 2278. [19] Hirsch JE ; Fay R M . Phys. Rev. Lett. 1986, 56, 2521. [20] Jarrell M. Phys. Rev. Lett. 1992, 69, 168. [21] W ahle J.; Blum er N.; Schlipf J.; Held K.; Vollhardt D. Phys. Rev. B 1998, 58, 12749. [22] Ulm ke M. Eur. Phys. J. B 1998, 1, 301. [23] Meyer D.; Nolting W. Phys. Rev. B 2000, 62, 5657. [24] Wegner T.; Pottho M.; Nolting W. Phys. Rev. B 1998, 57, 6211. [25] Byczuk K .; U lm ke M .; Vollhardt D . Phys. Rev. Lett. 2003, 90, 196403. [26] Am adon J.C.; Hirsch J.E. Phys. Rev. B 1996, 54, 6364. [27] Hirsch J.E. Phys. Rev. B 1999, 59, 6256. [28] Hirsch J.E. Phys. Rev. B 1989, 40, 2354. [29] Hirsch J.E. Phys. Rev. B 1989, 40, 9061. [30] Hirsch J.E. Phys. Rev. B 1991, 43, 705. [31] Kollar M .; Strack R .; Vollhardt D . Phys. Rev. B 1996, 53, 9225. [32] Strack R ; Vollhardt D . Phys. Rev. Lett. 1994, 72, 3425. [33] Gorski G.; M izia J. Physica B 2004, 344, 231. [34] Gorski G ; M izia J; Kucab K. Physica B 2003, 325, 106. [35] Vollhardt D.; Blumer N.; Held K.; Kollar M.; Schlipf J.; Ulmke M.; Wahle J. Adv. Solid State Phys. 1999, 38, 383. [36] Kollar M ; Vollhardt D Phys. Rev. B 2001, 63, 045107.

- [37] Barreteau C.; Desjonqueres M.C.; Ole A.M.; Spanjaard D. Phys. Rev. B 2004,69, 064432.
- [38], Saxena S.S.; Agarwal P.; Ahilan K.; Grosche F.M.; Haselwimmer R.K.W.; Steiner M.J.; Pugh E.; Walker IR.; Julian S.R.; Monthoux P.; Lonzarich G.G.; Huxley A.; Sheikin I.; Braithwaite D.; Flouquet J. Nature 2000, 406, 587.
- [39] AokiD .; Huxley A .; Ressouche E .; Braithwaite D .; Flouquet J.; Brison J-P .; Lhotel E .; Paulsen C . Nature 2001, 413, 613.

- [40] P eiderer C.; Uhlarz M.; Hayden S.M.; Vollmer R.; Lohneysen H.V.; Bernhoeft N.R.; Lonzarich G.G. Nature 2001, 412, 58.
- [41] Spalek J.; W robel P.; W ojcik W . Physica C 2003, 387, 1.
- [42] M izia J.; Gorski G.; Kucab K. phys. stat. sol. (b) 2002,229, 1221.
- [43] K yung B. Phys. Rev. B 2000, 62, 9083.
- [44] Micnas R.; Ranninger J.; Robaszkiewicz S. Rev. Mod. Phys. 1990, 62, 113.
- [45] CampbellD K ; GammelJ.T ; Loh JrE Y Phys. Rev. B 1988, 38, 12043.
- [46] Cam pbellD K ; Gam m elJ.T ; Loh Jr E Y . Phys. Rev. B 1990, 42, 475.
- [47] Hirsch J.E. Phys. Rev. B 1993, 59, 3327.
- [48] Hirsch J.E. Phys. Rev. B 2002, 65, 184502.
- [49] Gunnarsson O.; Christensen N.E. Phys. Rev. B 1990, 42, 2363.
- [50] Foglio M .; Falicov L. Phys. Rev. B 1979, 20, 4554.
- [51] Aligia A A ; Gagliano E ; Arrachea L ; Hallberg K . Eur. Phys. J. B 1998, 5, 371.
- [52] Soven P. Phys. Rev. 1967, 156, 809.
- [53] Plischke M.; Mattis D. Phys. Rev. B 1973, 7, 2430.
- [54] Brouers F.; Giner J.; Van der Rest J.J. Phys. F 1974, 4, 214.
- [55] M izia J. phys. stat. sol. (b) 1977, 84, 449.
- [56] K ubler J. Theory of Itinerant E lectron M agnetism ; International Series of M onographs in Physics; C larendon P ress, O xford, G B, 2000.
- [57] Mohn P. Magnetism in the Solid State; Spinger-Verlag, Berlin Heidelberg, , 2003.
- [58] K ittelCh. Introduction to Solid State Physics; John W iley and Sons, New York, Chicester, Brisbane, Toronto, Singapure 1996.
- [59] Morrish A.H. The Physical Principles of Magnetism; John W iley and Sons Inc., New York, US, 1965.
- [60] Levin K .; Bass R .; Bennem ann K H. Phys. Rev. B 1972, 6, 1865.
- [61] Fukuyam a H. Phys. Rev. B 1972, 5, 2872.
- [62] Hasegawa H.; Kanam ori J.J. Phys. Soc. Jap. 1971, 31, 382.
- [63] Kajzar F.; Mizia J.J. Phys. F 1977, 7, 1115.
- [64] Moriya T. Spin Fluctuations in Itinerant Electron Magnetism; Springer Verlag, Berlin, DE, 1985.
- [65] M izia J.J. Phys. F: Met. Phys. 1982, 12, 3053.
- [66] M izia J.; Rom anow ski S.J. phys. stat. sol. (b) 1994, 186, 225.
- [67] Bardeen J.; Cooper L.N.; Schrie er J.R. Phys. Rev. 1957, 108, 1175.
- [68] Micnas R.; Ranninger J.; Robaszkiewicz S. Phys. Rev. B 1989, 39, 11653.
- [69] Gorski G.; Mizia J.; Kucab K. Physica B 2003, 336, 308.
- [70] Hirsch J.E.; Marsiglio F. Phys. Rev. B 1989, 39, 11515.
- [71] Hirsch J.E. Phys. Rev. B 2000, 62, 14487.
- [72] Faw cett E Rev. M cd. Phys. 1988, 60, 209.
- [73] W eiss P.J. de Physique 1907, 6, 661.
- [74] Slater J.C. Phys. Rev. 1936, 49, 537.
- [75] Hubbard J. Phys. Rev. B 1979, 19, 2626.
- [76] Friedel J.J. Phys. I 1978, 39, 651.
- [77] Kajzar F.; Friedel J.J. Phys. I 1978, 39, 397.
- [78] Tallon JL.; Bernhard C.; Shaked H.; Hitterm an R.L.; Jorgensen JD. Phys. Rev. B 1995, 51, 12911.